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January 30, 2008



LM185-1.2/LM285-1.2/LM385-1.2 Micropower Voltage Reference Diode

General Description

The LM185-1.2/LM285-1.2/LM385-1.2 are micropower 2-terminal band-gap voltage regulator diodes. Operating over a 10μA to 20mA current range, they feature exceptionally low dynamic impedance and good temperature stability. On-chip trimming is used to provide tight voltage tolerance. Since the LM185-1.2 band-gap reference uses only transistors and resistors, low noise and good long term stability result.

Careful design of the LM185-1.2 has made the device exceptionally tolerant of capacitive loading, making it easy to use in almost any reference application. The wide dynamic operating range allows its use with widely varying supplies with excellent regulation.

The extremely low power drain of the LM185-1.2 makes it useful for micropower circuitry. This voltage reference can be used to make portable meters, regulators or general purpose analog circuitry with battery life approaching shelf life.

Further, the wide operating current allows it to replace older references with a tighter tolerance part.

The LM185-1.2 is rated for operation over a -55°C to 125°C temperature range while the LM285-1.2 is rated -40°C to 85°C and the LM385-1.2 0°C to 70°C. The LM185-1.2/LM285-1.2 are available in a hermetic TO-46 package and the LM285-1.2/LM385-1.2 are also available in a low-cost TO-92 molded package, as well as SO and SOT-23. The LM185-1.2 is also available in a hermetic leadless chip carrier package.

Features

- ±1% and 2% initial tolerance
- Operating current of 10µA to 20mA
- 1Ω dynamic impedance
- Low temperature coefficient
- Low voltage reference—1.235V
- 2.5V device and adjustable device also available
- LM185-2.5 series and LM185 series, respectively

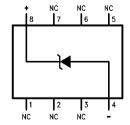
Connection Diagrams

T0-92 Plastic Package (Z)



Bottom View
Order Number LM285Z-1.2,
LM285BXZ-1.2, LM285BYZ-1.2
LM385Z-1.2, LM385BZ-1.2
LM385BXZ-1.2 or LM385BYZ-1.2
See NS Package Number Z03A

SO Package



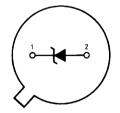
Order Number LM285M-1.2, LM285BXM-1.2, LM285BYM-1.2 LM385M-1.2, LM385BM-1.2 LM385BXM-1.2 or LM385BYM-1.2 See NS Package Number M08A



* Pin 3 is attached to the Die Attach Pad (DAP) and should be connected to Pin 2 or left floating.

Order Number LM385M3-1.2 See NS Package Number MF03A

> TO-46 Metal Can Package (H)



Bottom View
Order Number LM185H-1.2, LM185H-1.2/883,
LM185BXH-1.2, LM185BYH-1.2
LM285H-1.2 or LM285BXH-1.2
See NS Package Number H02A

Absolute Maximum Ratings (Note 1)

If Military/Aerospace specified devices are required, please contact the National Semiconductor Sales Office/ Distributors for availability and specifications.

Reverse Current 30mA **Forward Current** 10mA

Operating Temperature Range (Note 3)

LM185-1.2 -55°C to +125°C LM285-1.2 -40°C to +85°C LM385-1.2 0°C to 70°C

ESD Susceptibility (Note 9) 2kV -55°C to +150°C Storage Temperature

Soldering Information

260°C TO-92 package: 10 sec. TO-46 package:10 sec. 300°C

SO and SOT Pkg.

Vapor phase (60 sec.) 215°C 220°C Infrared (15 sec.)

See AN-450 "Surface Mounting Methods and Their Effect on Product Reliability" for other methods of soldering

surface mount devices.

Electrical Characteristics (Note 4)

			LM185-1.2 LM185BX-1.2 LM185BY-1.2 LM285-1.2 LM285BX-1.2 LM285BY-1.2		LM385B-1.2 LM385BX-1.2 LM385BY-1.2		LM385-1.2		Units (Limit)
Parameter	Conditions	Тур							
			Tested Limit (Notes 5,	Design Limit (Note 6)	Tested Limit (Note 5)	Design Limit (Note 6)	Tested Limit (Note 5)	Design Limit (Note 6)	
Reverse Breakdown	T _A = 25°C,	1.23 5	1.223		1.223		1.205		V(Min)
Voltage	10μA ≤ I _R ≤ 20mA		1.247		1.247		1.260		V(Max)
Minimum Operating		8	10	20	15	20	15	20	μA
Current	LM385M3-1.2						10	15	(Max)
Reverse Breakdown Voltage Change	10μA ≤ I _R ≤ 1mA		1	1.5	1	1.5	1	1.5	mV (Max)
with Current	1mA ≤ I _R ≤ 20mA		10	20	20	25	20	25	mV (Max)
Reverse Dynamic Impedance	I _R = 100μA, f = 20Hz	1							Ω
Wideband Noise (rms)	$I_R = 100\mu A$, $10Hz \le f \le 10kHz$	60							μV
Long Term Stability	$I_R = 100\mu A, T = 1000 Hr,$ $T_A = 25^{\circ}C \pm 0.1^{\circ}C$	20							ppm
Average Temperature	I _R = 100μA								
Coefficient (Note 7)	X Suffix Y Suffix All Others		30 50	150	30 50	150		150	ppm/°C ppm/°C ppm/°C
	All Others			150		150		150	(Max)

Note 1: Absolute Maximum Ratings indicate limits beyond which damage to the device may occur. Operating Ratings indicate conditions for which the device is intended to be functional, but do not guarantee specific performance limits. For guaranteed specifications and test conditions, see the Electrical Characteristics. The guaranteed specifications apply only for the test conditions listed.

Note 2: Refer to RETS185H-1.2 for military specifications.

Note 3: For elevated temperature operation, T_i max is:

LM185 150°C LM285 125°C LM385 100°C

Thermal Resistance	TO-92	TO-46	SO-8	SOT23
θ _{JA} (junction to ambient)	180°C/W (0.4 leads)	440°C/W	165°C/W	283°C/W
	170°C/W (0.125 leads)			
θ_{JC} (junction to case)	N/A	80°C/W	N/A	N/A

Note 4: Parameters identified with boldface type apply at temperature extremes. All other numbers apply at $T_A = T_J = 25^{\circ}$ C.

Note 5: Guaranteed and 100% production tested.

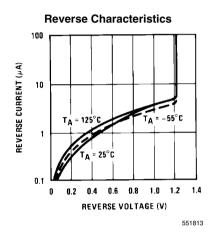
Note 6: Guaranteed, but not 100% production tested. These limits are not used to calculate average outgoing quality levels.

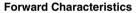
Note 7: The average temperature coefficient is defined as the maximum deviation of reference voltage at all measured temperatures between the operating T_{MAX} and T_{MIN}, divided by T_{MAX} – T_{MIN}. The measured temperatures are –55°C, –40°C, 0°C, 25°C, 70°C, 85°C, 125°C.

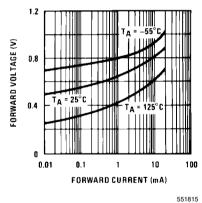
Note 8: A military RETS electrical specification is available on request.

Note 9: The human body model is a 100 pF capacitor discharged through a 1.5 k Ω resistor into each pin.

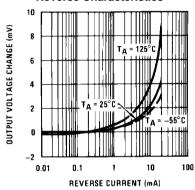
Typical Performance Characteristics



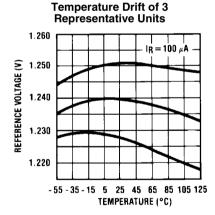




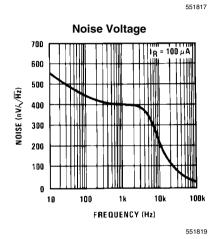
Reverse Characteristics

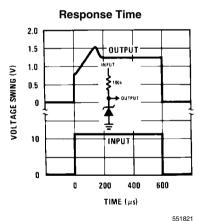


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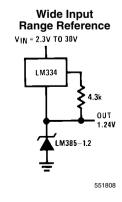


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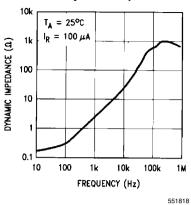




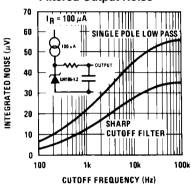
Typical Applications



Reverse Dynamic Impedance

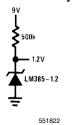


Filtered Output Noise



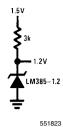
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Micropower Reference from 9V Battery

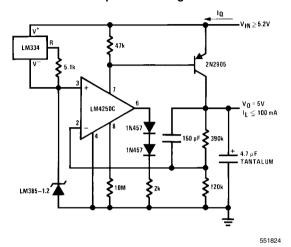


Reference from

1.5V Battery

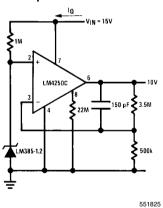


Micropower* 5V Regulator



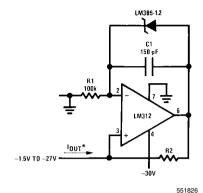
$^*I_Q \simeq 30 \mu A$

Micropower* 10V Reference

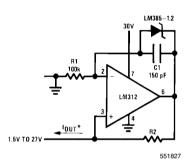


*I_Q ≃20µA standby current

Precision 1µA to 1mA Current Sources



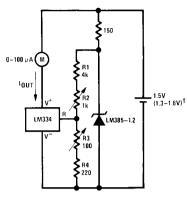
*I_{OUT} = 1.23V



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METER THERMOMETERS

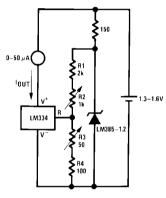
0°C-100°C Thermometer



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Calibration

- 1. Short LM385-1.2, adjust R3 for $I_{OUT}\!\!=\!$ temp at $1\mu A/^{\circ} K$
- 2. Remove short, adjust R2 for correct reading in centigrade 0°F–50°F Thermometer

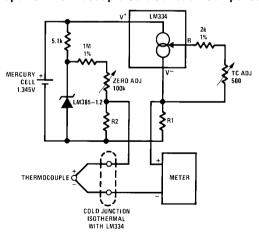


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Calibration

- 1. Short LM385-1.2, adjust R3 for $I_{OUT} = temp \ at \ 1.8 \mu A/^{\circ} K$
- 2. Remove short, adjust R2 for correct reading in °F

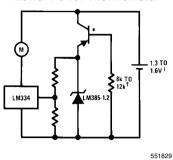
Micropower Thermocouple Cold Junction Compensator



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†I_O at 1.3V 500μA I_O at 1.6V 2.4mA

Lower Power Thermometer



*2N3638 or 2N2907 select for inverse H_{FE} 5

†Select for operation at 1.3V

 $\sharp I_Q \simeq 600 \mu A$ to $900 \mu A$

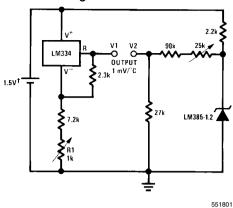
Adjustment Procedure

- 1. Adjust TC ADJ pot until voltage across R1 equals Kelvin temperature multiplied by the thermocouple Seebeck coefficient.
- 2. Adjust zero ADJ pot until voltage across R2 equals the thermocouple Seebeck coefficient multiplied by 273.2.

Thermocoup le	Seebeck	R1	R2	Voltage	Voltage
Туре	Coefficient	(Ω)	(Ω)	Across R1	Across R2
	(µV/°C)			@ 25°C	(mV)
				(mV)	
J	52.3	52 3	1.2 4k	15.60	14.32
Т	42.8	43 2	1k	12.77	11.78
K	40.8	41 2	95 3Ω	12.17	11.17
S	6.4	63. 4	15 0Ω	1.908	1.766

Typical supply current 50µA

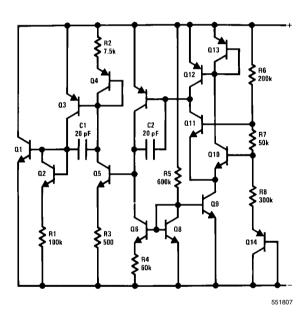
Centigrade Thermometer



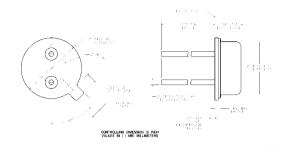
Calibration

- 1. Adjust R1 so that V1 = temp at $1mV/^{\circ}K$

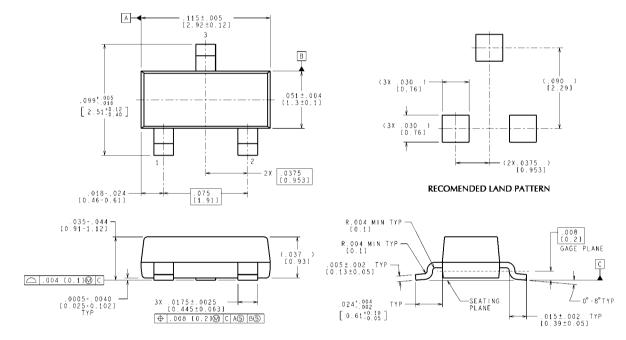
2. Adjust V2 to 273.2mV †I_Q for 1.3V to 1.6V battery voltage = 50μA to 150μA **Schematic Diagram**



Physical Dimensions inches (millimeters) unless otherwise noted



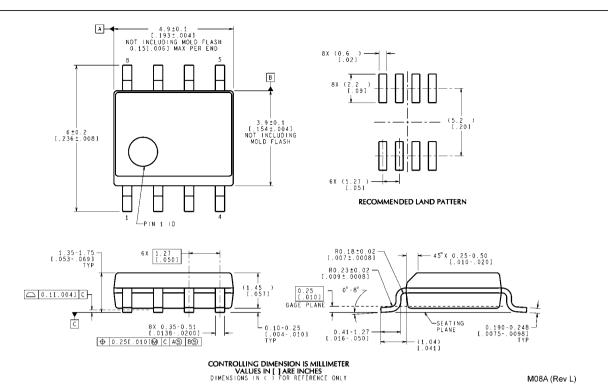
TO-46 Metal Can Package (H)
Order Number LM185H-1.2, LM185H-1.2/883, LM185BXH-1.2, LM185BYH-1.2, LM285H-1.2, or LM285BXH-1.2
NS Package Number H02A



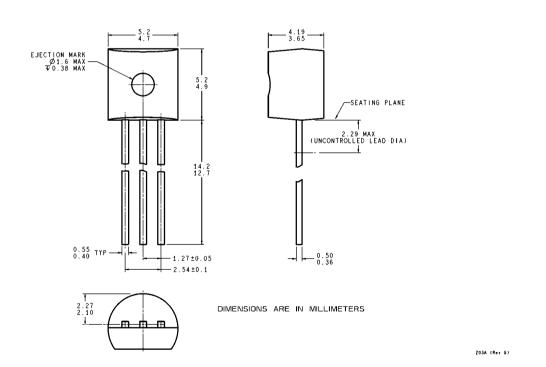
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MF03A (Rev B)

SOT-23 Package (M3) Order Number LM385M3-1.2 NS Package Number MF03A



Small Outline (SO-8) Package Order Number LM285M-1.2, LM285BXM-1.2, LM285BYM-1.2 LM385M-1.2, LM385BM-1.2, LM385BXM-1.2, LM385BYM-1.2 NS Package Number M08A



TO-92 Plastic Package (Z)
Order Number LM285Z-1.2, LM285BXZ-1.2
LM285BYZ-1.2, LM385Z-1.2, LM385BZ-1.2
LM385BXZ-1.2 or LM385BYZ-1.2
NS Package Number Z03A

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Notes

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